

Silicon NPN Epitaxial

REJ03G0786-0200 (Previous ADE-208-1148) Rev.2.00 Aug.10.2005

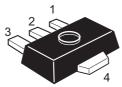
Application

• Low frequency power amplifier

• Complementary pair with 2SB1002

Outline

RENESAS Package code: PLZZ0004CA-A (Package name: UPAK $^{\textcircled{R}}$)



- 1. Base 2. Collector 3. Emitter
- 4. Collector (Flange)

*UPAK is a trademark of Renesas Technology Corp.

Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Collector to base voltage	V _{CBO}	100	V
Collector to emitter voltage	V _{CEO}	50	V
Emitter to base voltage	V _{EBO}	6	V
Collector current	Ic	1	А
Collector peak current	i _{C(peak)} * ¹	1.5	А
Collector power dissipation	Pc*2	1	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. $PW \le 10 \text{ ms}$, $Duty cycle \le 20\%$

2. Value on the alumina ceramic board (12.5 x 20 x 0.7 mm)



Electrical Characteristics

(Ta = 25)	°C)
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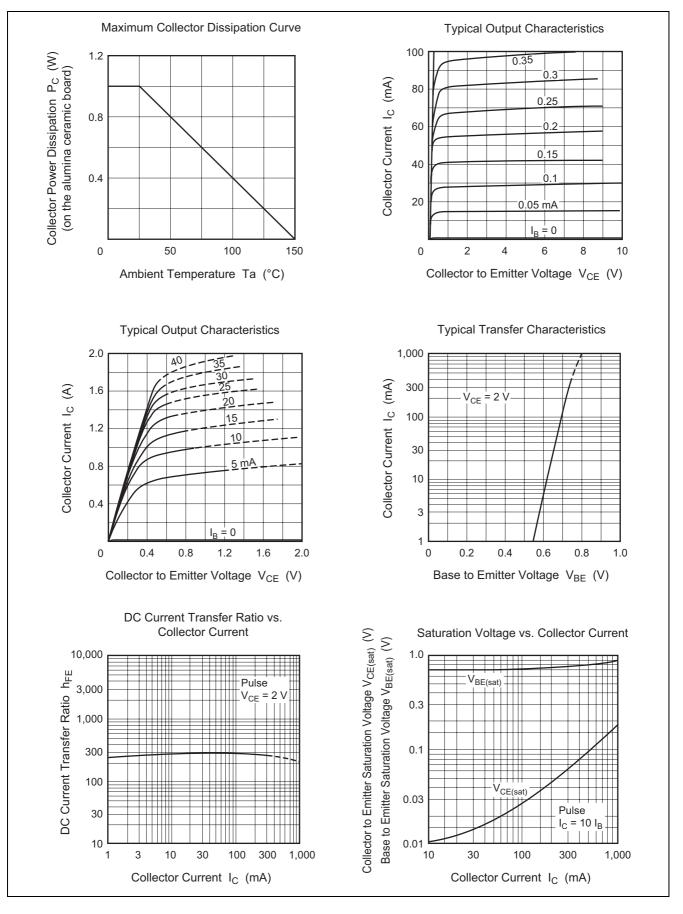
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V _{(BR)CBO}	100	—	—	V	I _C = 10 μA, I _E = 0
Collector to emitter breakdown voltage	V _{(BR)CEO}	50	—	—	V	I _C = 1 mA, R _{BE} = ∞
Emitter to base breakdown voltage	V _{(BR)EBO}	6	_	_	V	$I_{\rm E}$ = 10 μ A, $I_{\rm C}$ = 0
Collector cutoff current	I _{CBO}	_	_	0.1	μA	$V_{CB} = 80 \text{ V}, I_E = 0$
Emitter cutoff current	I _{EBO}	_	_	0.1	μA	$V_{EB} = 4 V, I_{C} = 0$
DC current transfer ratio	h _{FE} * ¹	160	_	500		V _{CE} = 2 V, I _C = 0.1 A
Collector to emitter saturation voltage	V _{CE(sat)}	_	_	0.3	V	$I_{\rm C}$ = 1 A, $I_{\rm B}$ = 0.1 A, Pulse
Base to emitter saturation voltage	V _{BE(sat)}	_	_	1.2	V	$I_{\rm C}$ = 1 A, $I_{\rm B}$ = 0.1 A, Pulse
Gain bandwidth product	f⊤	_	100	_	MHz	V_{CE} = 2 V, I_C = 10 mA, Pulse
Collector output capacitance	Cob	_	20		pF	V_{CB} = 10 V, I _E = 0, f = 1 MHz

Note: 1. The 2SD1368 is grouped by h_{FE} as follows.

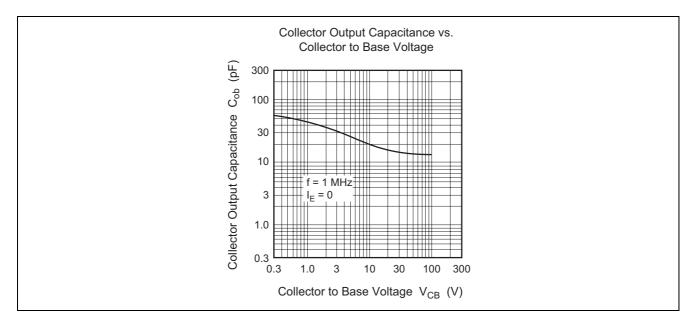
Mark	СВ	CC	
h _{FE}	160 to 320	250 to 500	



Main Characteristics

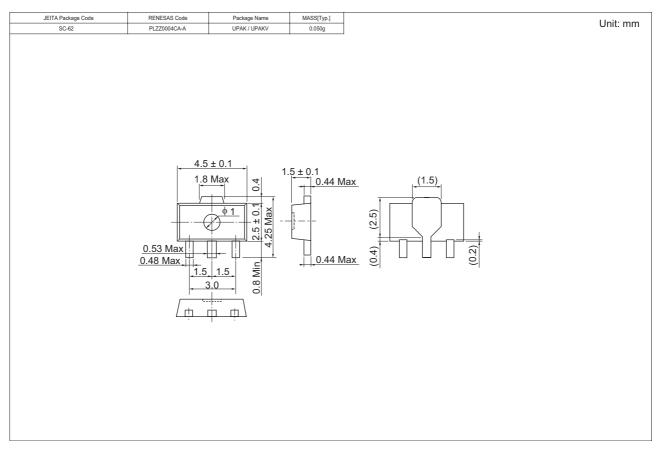








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SD1368CBTL-E	1000	φ 178 mm Reel, 12 mm Emboss Taping
2SD1368CCTL-E		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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